






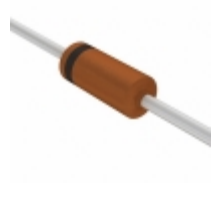


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|---|---|
|  | <p>BZX55C5V6</p> |
| | <p>Hersteller-Teilenummer: BZX55C5V6</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: DIODE ZENER 5.6V 500MW DO35</p> <p>Datenblätter:  BZX55C5V6.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8108 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|--|
| Teilenummer | BZX55C5V6 |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | DIODE ZENER 5.6V 500MW DO35 |
| Kategorie | Diskrete Halbleiterprodukte > Dioden - Zener - Single |
| Teilstatus | 8108 pcs Stock |
| detaillierte Beschreibung | Zener Diode 5.6V 500mW ±7% Through Hole DO-35 |
| Serie | - |
| Betriebstemperatur | -65°C ~ 200°C |
| Befestigungsart | Through Hole |
| Leistung - max | 500mW |
| Toleranz | ±7% |
| Verpackung / Gehäuse | DO-204AH, DO-35, Axial |
| Supplier Device-Gehäuse | DO-35 |
| Spannung - Forward (Vf) (Max) @ If | 1.3V @ 100mA |
| Strom - Sperrleckstrom @ Vr | 100nA @ 1V |
| Spannung - Zener (Nom) (Vz) | 5.6V |
| Impedanz (Max) (Zzt) | 25 Ohms |
| Verpackung | Bulk |
| Basisteilenummer | BZX55C5V6 |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |

BZX55C5V6 ist neu im Original, Suche BZX55C5V6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie BZX55C5V6 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage BZX55C5V6: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|---|---|
|  <p>BZX55C5V1_T50A AMI Semiconductor / ON Semiconductor DIODE ZENER 5.1V 500MW DO35</p> |  <p>BZX55C5V1_T50R AMI Semiconductor / ON Semiconductor DIODE ZENER 5.1V 500MW DO35</p> |  <p>BZX55C5V6-TAP Vishay / Semiconductor - Diodes Division DIODE ZENER 5.6V 500MW DO35</p> |  <p>BZX55C5V6-TR Vishay / Semiconductor - Diodes Division DIODE ZENER 5.6V 500MW DO35</p> |
|  <p>BZX55C5V6-TR Electro-Films (EFI) / Vishay DIODE ZENER 5.6V 500MW DO35</p> |  <p>BZX55C5V6 A0G TSC (Taiwan Semiconductor) DIODE ZENER 5.6V 500MW DO35</p> |  <p>BZX55C5V1_T50R Fairchild/ON Semiconductor DIODE ZENER 5.1V 500MW DO35</p> |  <p>BZX55C5V6 Fairchild/ON Semiconductor DIODE ZENER 5.6V 500MW DO35</p> |

heiße Teile

Mehr

| | | | | |
|--|--|---|--|---|
|  BZX55C24 |  BZX55C24V |  BZX55C27 |  BZX55C27 |  BZX55C27V |
|  BZX55C33V-TAP |  BZX55C36-TAP |  BZX55C36-TAP |  BZX55C39-TAP |  BZX55C39-TAP |
|  BZX55C3V3 |  BZX55C3V3 |  BZX55C3V3-TAP |  BZX55C3V3-TAP |  BZX55C3V6-TAP |
|  BZX55C3V6-TAP |  BZX55C3V9 |  BZX55C3V9 |  BZX55C4V3 |  BZX55C4V3 |
|  BZX55C5V1 |  BZX55C5V1 |  BZX55C5V1-TAP |  BZX55C5V1-TAP |  BZX55C5V6 |
|  BZX55C68-TAP |  BZX55C68-TAP |  BZX55C6V2 |  BZX55C6V2 |  BZX55C6V2-TAP |
|  BZX55C6V2-TAP |  BZX55C6V8 |  BZX55C6V8 |  BZX55C7V5-TAP |  BZX55C7V5-TAP |
|  BZX55C7V5-TR |  BZX55C7V5-TR |  BZX55C9V1 |  BZX55C9V1 |  BZX55C9V1-TAP |
|  BZX55C9V1-TAP |  BZX55C9V1ST |  BZX584-C5V1 |  BZX584-C5V6 |  BZX584B20-7-F |
|  BZX584B5V1-7-F |  BZX584B5V6-7-F |  BZX584C10 |  BZX584C12 |  BZX584C12-02VGS08 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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